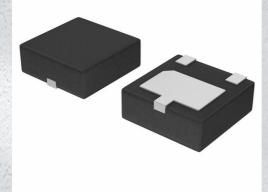


# NSS40501UW3T2G Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	NSS40501UW3T2G-DG
Manufacturer	onsemi
Manufacturer Product Number	NSS40501UW3T2G
Description	TRANS NPN 40V 5A 3WDFN
Detailed Description	Bipolar (BJT) Transistor NPN 40 V 5 A 150MHz 875 m W Surface Mount 3-WDFN (2x2)

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
NSS40501UW3T2G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	5 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
40 V	150mV @ 400mA, 4A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	200 @ 2A, 2V
Power - Max:	Frequency - Transition:
875 mW	150MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
3-WDFN Exposed Pad	3-WDFN (2x2)
Base Product Number:	
NSS40501	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

# NSS40501UW3, NSV40501UW3

# 40 V, 5.0 A, Low V<sub>CE(sat)</sub> NPN Transistor

ON Semiconductor's e<sup>2</sup>PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers. Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

<b>MAXIMUM RATINGS</b> ( $T_A = 25^{\circ}C$ )				
Rating	Symbol	Max	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	40	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc	
Collector Current – Continuous	Ι <sub>C</sub>	5.0	Adc	
Collector Current – Peak	I <sub>CM</sub>	7.0	А	
Electrostatic Discharge	ESD	HBM CI MM CI		

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub> (Note 1)	875 7.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	143	°C/W
Total Device Dissipation, $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub> (Note 2)	1.5 11.8	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	85	°C/W
Thermal Resistance, Junction-to-Lead #3	$R_{\theta JL}$ (Note 2)	23	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

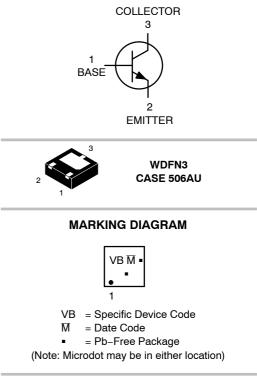
FR-4 @ 100 mm<sup>2</sup>, 1 oz copper traces.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz copper traces.



#### **ON Semiconductor®**

http://onsemi.com

#### 40 VOLTS, 5.0 AMPS NPN LOW V<sub>CE(sat)</sub> TRANSISTOR EQUIVALENT $\hat{R}_{DS(on)}$ 38 m $\Omega$



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS40501UW3T2G	WDFN3 (Pb-Free)	3000/ Tape & Reel
NSV40501UW3T2G	WDFN3 (Pb-Free)	3000/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### NSS40501UW3, NSV40501UW3

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS					1
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	40	-	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)CBO</sub>	40	-	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	6.0	-	_	Vdc
Collector Cutoff Current $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	_	-	0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 6.0 Vdc)	I <sub>EBO</sub>	_	-	0.1	μAdc
ON CHARACTERISTICS					
$ \begin{array}{l} \text{DC Current Gain (Note 3)} \\ (I_{C} = 10 \text{ mA}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 3.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 3.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \end{array} $	h <sub>FE</sub>	200 200 200 200 180	- 320 305 295	- - - - -	
$\begin{array}{l} \mbox{Collector}-\mbox{Emitter Saturation Voltage (Note 3)} \\ (I_{C}=0.1\ A,\ I_{B}=0.010\ A) \\ (I_{C}=1.0\ A,\ I_{B}=0.100\ A) \\ (I_{C}=1.0\ A,\ I_{B}=0.010\ A) \\ (I_{C}=2.0\ A,\ I_{B}=0.020\ A) \\ (I_{C}=3.0\ A,\ I_{B}=0.030\ A) \\ (I_{C}=4.0\ A,\ I_{B}=0.400\ A) \end{array}$	V <sub>CE(sat)</sub>	- - - - -	0.006 0.038 0.060 0.097 0.130 0.110	0.010 0.045 0.080 0.120 0.160 0.150	V
Base – Emitter Saturation Voltage (Note 3) ( $I_C = 1.0 \text{ A}, I_B = 0.01 \text{ A}$ )	V <sub>BE(sat)</sub>	-	0.760	0.900	V
Base – Emitter Turn–on Voltage (Note 3) ( $I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ )	V <sub>BE(on)</sub>	-	0.730	0.900	V
Cutoff Frequency (I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 5.0 V, f = 100 MHz)	f <sub>T</sub>	150	-	_	MHz
Input Capacitance (V <sub>EB</sub> = 0.5 V, f = 1.0 MHz)	Cibo	_		650	pF
Output Capacitance (V <sub>CB</sub> = 3.0 V, f = 1.0 MHz)	Cobo	_		70	pF
SWITCHING CHARACTERISTICS				•	
Delay (V <sub>CC</sub> = 30 V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>d</sub>	-	-	90	ns
Rise ( $V_{CC}$ = 30 V, $I_{C}$ = 750 mA, $I_{B1}$ = 15 mA)	t <sub>r</sub>	-	-	100	ns
Storage (V <sub>CC</sub> = 30 V, $I_C$ = 750 mA, $I_{B1}$ = 15 mA)	t <sub>s</sub>	-	-	1050	ns
Fall (V <sub>CC</sub> = 30 V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	tf	_	-	100	ns

3. Pulsed Condition: Pulse Width = 300  $\mu sec,$  Duty Cycle  $\leq$  2%.

NSS40501UW3, NSV40501UW3

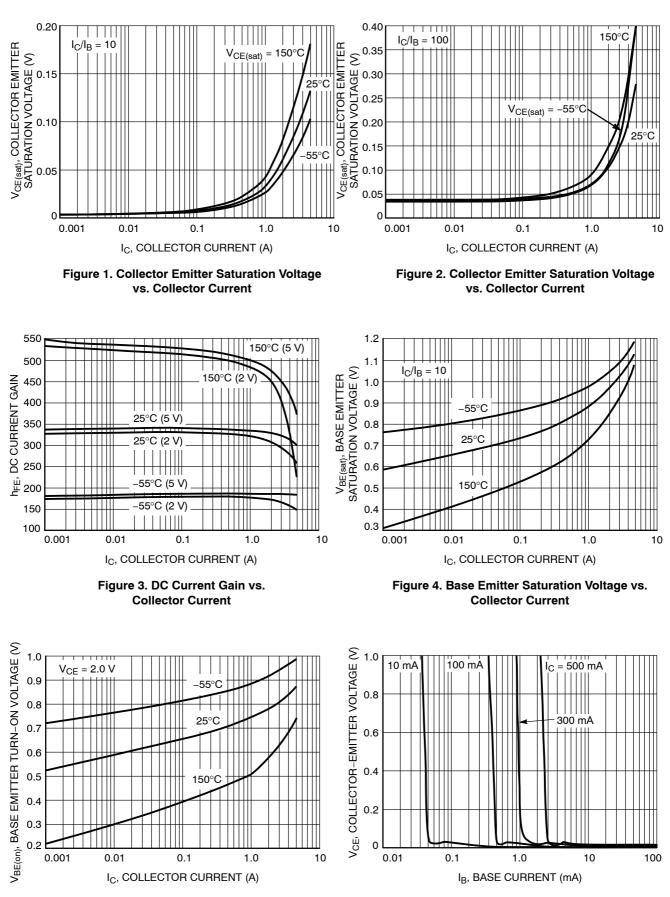


Figure 5. Base Emitter Turn-On Voltage vs. Collector Current

Figure 6. Saturation Region

NSS40501UW3, NSV40501UW3

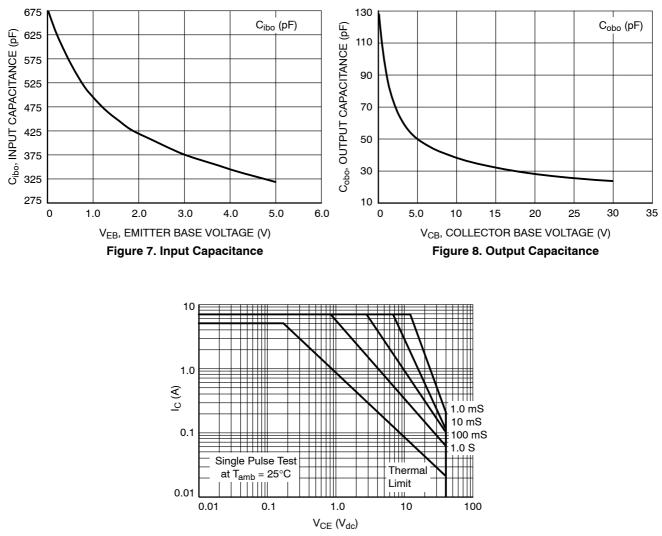


Figure 9. Safe Operating Area

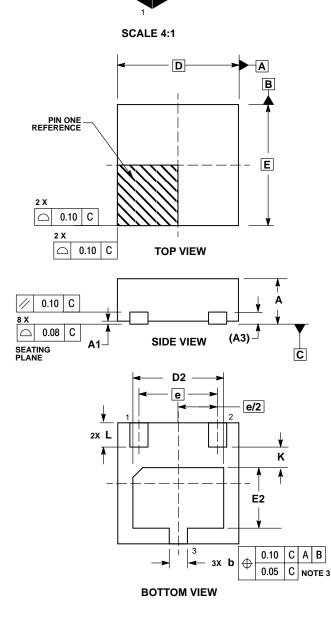


### **MECHANICAL CASE OUTLINE**

PACKAGE DIMENSIONS

WDFN3 2x2, 1.3P CASE 506AU **ISSUE A** 

DATE 18 AUG 2016



NOTES:

- DIES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994 .
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO DI ATTECT.

CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS 4 THE TERMINALS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00		0.05	0.000		0.002
A3		0.20 REF			0.008 REF	
b	0.25	0.30	0.35	0.010	0.012	0.014
D		2.00 BSC			0.079 BSC	;
D2	1.40	1.50	1.60	0.055	0.059	0.063
E		2.00 BSC			0.079 BSC	;
E2	0.90	1.00	1.10	0.035	0.039	0.043
е		1.30 BSC			0.051 BSC	;
ĸ		0.35 REF			0.014 REF	
L	0.35	0.40	0.45	0.014	0.016	0.018

#### GENERIC **MARKING DIAGRAM\***



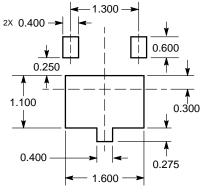
XX = Specific Device Code

= Date Code Μ

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " .", may or may not be present.

#### SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON21416D Electronic versions are uncontrolled except when accessed directly from the Document Re Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	WDFN3 2X2, 1.3P		PAGE 1 OF 1

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NSS40501UW3T2G onsemi TRANS NPN 40V 5A 3WDFN

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